

IN THE CLAIMS:

Please amend claims 1-3 in "clean" format, as follows:

1. (Amended) A semiconductor device comprising:

a thin film transistor provided between an element to be driven which operates based on supplied power and which comprises an emissive element which includes an emissive element layer between a first electrode and a second electrode and a power supply line for supplying power to said element to be driven, for controlling the power supplied to said element to be driven; wherein

the thin film transistor and said first electrode of corresponding element to be driven are electrically connected to each other by a wiring layer;

said wiring layer is connected to said thin film transistor through a contact hole formed on a first insulation layer which covers said thin film transistor and is connected to said first electrode of said element to be driven formed on a second insulation layer through a contact hole formed on said second insulation layer which is formed above said wiring layer to cover said wiring layer;

the contact position between the wiring layer and the thin film transistor is placed to be distant from the contact position between the wiring layer and said element to be driven in the horizontal direction; and

said emissive element layer and said second electrode are layered on said first electrode formed on said second insulation layer.

2. (Amended) A semiconductor device comprising: a thin film transistor provided between an element to be driven which operates based on supplied power and a power supply line for supplying power to said element to be driven, for controlling the power supplied to said element to be driven; wherein

the thin film transistor and corresponding element to be driven are electrically connected to each other by a wiring layer;

the contact position between the wiring layer and the thin film transistor is placed to be distant from the contact position between the wiring layer and said element to be driven;

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said element to be driven is an emissive element which includes an emissive element layer between a first electrode and a second electrode;

a contact hole is formed on an insulation layer which is formed above said wiring layer, said wiring layer being connected through the contact hole to said first electrode of said emissive element which is formed on top of said insulation layer and covering said contact hole;

at least the contact hole region of said first electrode to be connected to said wiring layer is filled with a flattening layer; and

said emissive element layer and said second electrode are formed above said first electrode and said flattening layer filling the contact hole region of said first electrode.

3. (Amended) A semiconductor device comprising:

a thin film transistor for controlling power supplied to an element to be driven which operates based on the supplied power and which includes an emissive element layer between a first electrode and a second electrode, said thin film transistor provided between said element to be driven and a power supply line for supplying power to said element to be driven; wherein

the thin film transistor and corresponding element to be driven are directly or indirectly and electrically connected to each other at a contact hole formed on an insulation layer for separating said thin film transistor which is formed at a lower layer and said element to be driven;

said first electrode is formed on said insulation layer to cover said contact hole;

a recess of said first electrode formed in a region at least covering said contact hole is covered by a flattening layer; and

said emissive element layer is formed above said first electrode and said flattening layer.

Please add claims 5-6, as follows:

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5. (Newly Added) A semiconductor device according to claim 2, wherein said element to be driven is an organic electroluminescence element which uses an organic compound in an emissive layer.

6. (Newly Added) A semiconductor device according to claim 3, wherein said element to be driven is an organic electroluminescence element which uses an organic compound in an emissive layer.

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